

General Purpose Transister (dual transistors)

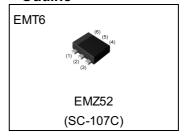
<For Tr1(NPN)>

Parameter	Value
V _{CEO}	50V
I _C	100mA

<For Tr2(PNP)>

Parameter	Value
V _{CEO}	-50V
I _C	-100mA

Outline



Features

- 1) General Purpose.
- 2) 2SAR523 and 2SCR523 chips in one package.
- 3) Transister elements are independent, eliminating interface.
- 4) Mounting cost and area can be cut in half.
- 5) Lead Free/RoHS Compliant.

•Inner circuit

- (1) Tr1(NPN) Emitter
- (2) Tr1(NPN) Base
- (3) Tr2(PNP) Collector
- (4) Tr2(PNP) Emitter

(6) Tr1(NPN) Collector

- (5) Tr2(PNP) Base
- (6) (5) (4) Tr1

 Tr2

 (1) (2) (3)

Application

Switching, LED driver

Packaging specifications

Part No.	Package	Package size	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit.(pcs)	Marking
EMZ52	EMT6	1616	T2R	180	8	8000	Z52

● Absolute maximum ratings (T_a = 25°C)

Parameter	Symbol	Tr1(NPN)	Tr2(PNP)	Unit
Collector-base voltage	V_{CBO}	50	-50	V
Collector-emitter voltage	V_{CEO}	50	-50	V
Emitter-base voltage	V_{EBO}	5	-5	V
Callantan arresent	I _C	100	-100	mA
Collector current	I _{CP} *1	200	-200	mA
Power dissipation	P _D *2*3	150(Total)	mW
Junction temperature	Tj	15	50	°C
Range of storage temperature	T _{stg}	-55 to	+150	°C

ullet Electrical characteristics (T_a = 25°C) <For Tr1(NPN)>

Dorameter	Cumbal	Conditions	Values			Unit	
Parameter	Symbol	Conditions	Min.	Тур.	Max.	ax.	
Collector-base breakdown voltage	BV _{CBO}	I _C = 50μA	50	-	-	V	
Collector-emitter breakdown voltage	BV _{CEO}	I _C = 1mA	50	-	-	V	
Emitter-base breakdown voltage	BV_{EBO}	I _E = 50μA	5	-	-	V	
Collector cut-off current	I _{CBO}	V _{CB} = 50V	-	-	0.1	μA	
Emitter cut-off current	I _{EBO}	V _{EB} = 5V	-	-	0.1	μA	
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C = 50$ mA, $I_B = 5$ mA	-	0.15	0.40	V	
DC current gain	h _{FE}	V_{CE} = 6V, I_{C} = 1mA	120	-	560	-	
Transition frequency	f _T	$V_{CE} = 10V, I_{E} = -10mA,$ f = 100MHz	-	350	-	MHz	
Output capacitance	C _{ob}	$V_{CB} = 10V$, $I_E = 0A$, $f = 1MHz$	-	1.6	-	pF	

ullet Electrical characteristics (T_a = 25°C) <For Tr2(PNP)>

Parameter	Symbol	Conditions	Values			Unit
Farameter	Symbol	Conditions	Min.	Тур.	Max.	
Collector-base breakdown voltage	BV_{CBO}	I _C = -50μA	-50	-	-	V
Collector-emitter breakdown voltage	BV _{CEO}	I _C = -1mA	-50	-	-	V
Emitter-base breakdown voltage	BV_{EBO}	I _E = -50μA	-5	-	-	V
Collector cut-off current	I _{CBO}	V _{CB} = -50V	1	-	-0.1	μA
Emitter cut-off current	I _{EBO}	V _{EB} = -5V	1	-	-0.1	μA
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C = -50 \text{mA}, I_B = -5 \text{mA}$	-	-0.15	-0.40	V
DC current gain	h _{FE}	$V_{CE} = -6V, I_{C} = -1mA$	120	-	560	-
Transition frequency	f _T	$V_{CE} = -10V, I_{E} = 10mA,$ f = 100MHz	-	300	-	MHz
Output capacitance	C _{ob}	$V_{CB} = -10V$, $I_E = 0A$, $f = 1MHz$	-	2	-	pF

^{*1} Pw=1ms Single Pulse



^{*2} Each terminal mounted on a reference footprint

^{*3 120}mW per element must not be exceeded.

● Electrical characteristic curves(Ta=25°C) <For Tr1(NPN)>

Fig.1 Grounded Emitter Propagation
Characteristics

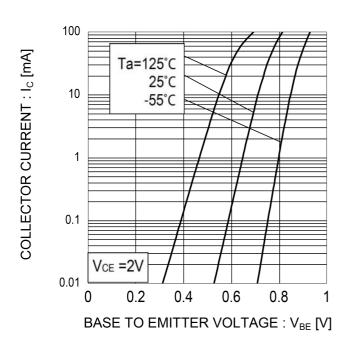


Fig.2 Typical Output Characteristics

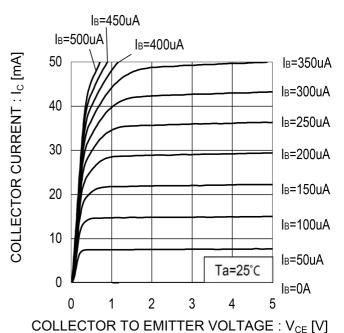


Fig.3 DC Current Gain vs. Collector Current(I)

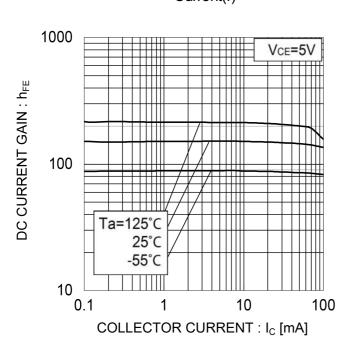
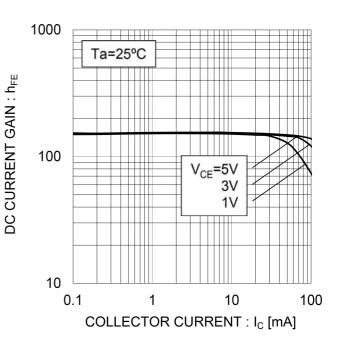


Fig.4 DC Current Gain vs. Collector Current(II)



● Electrical characteristic curves (T_a=25°C) <For Tr1(NPN)>

Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current(I)

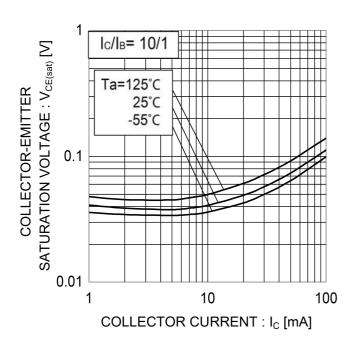


Fig.6 Collector-Emitter Saturation Voltage vs. Collector Current(II)

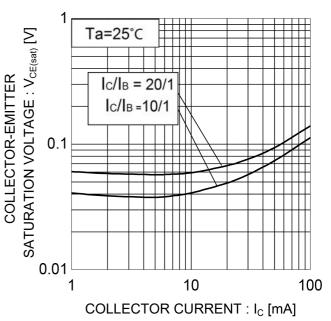


Fig.7 Base-Emitter Saturation Voltage vs.
Collector Current

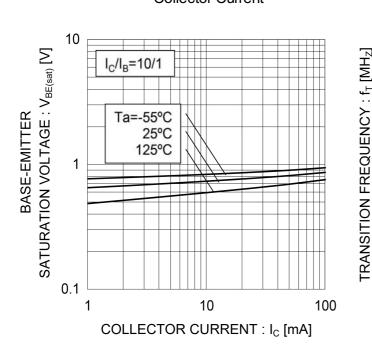
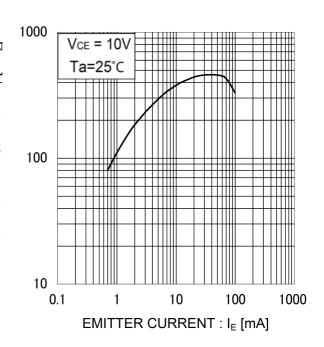


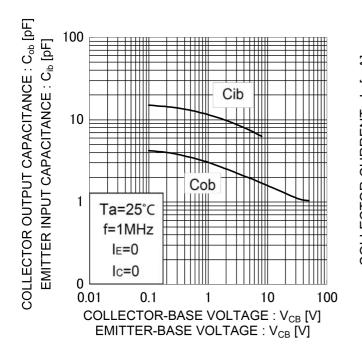
Fig.8 Gain Bandwidth Product vs. Emitter
Current

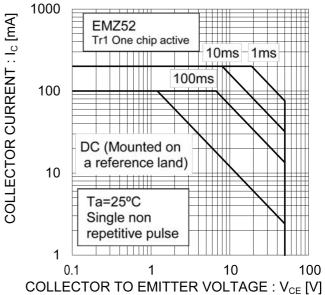


● Electrical characteristic curves (T_a =25°C) <For Tr1(NPN)>

Fig.9 Emitter input capacitance vs. Emitter-Base Voltage Collector output capacitance vs. Collector-

Fig.10 Safe Operating Area





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● Electrical characteristic curves (T_a =25°C) <For Tr2(PNP)>

Fig.1 Grounded Emitter Propagation
Characteristics

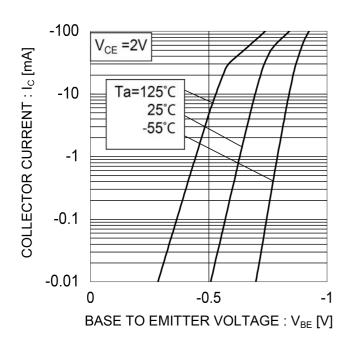
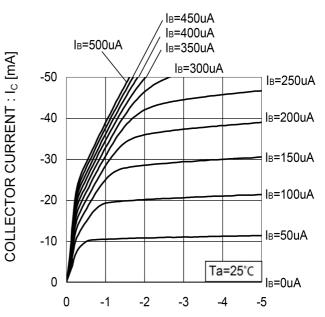


Fig.2 Typical Output Characteristics



COLLECTOR TO EMITTER VOLTAGE : $V_{CE}\left[V\right]$

Fig.3 DC Current Gain vs. Collector Current(I)

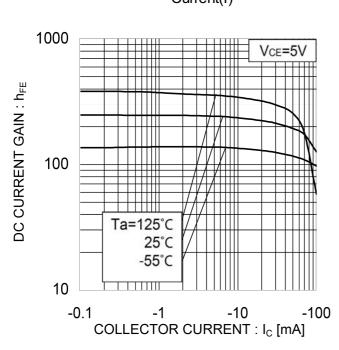
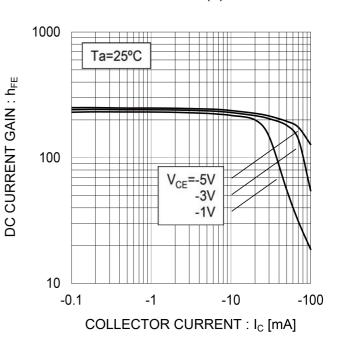


Fig.4 DC Current Gain vs. Collector Current(II)



● Electrical characteristic curves (T_a = 25°C) <For Tr2(PNP)>

Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current(I)

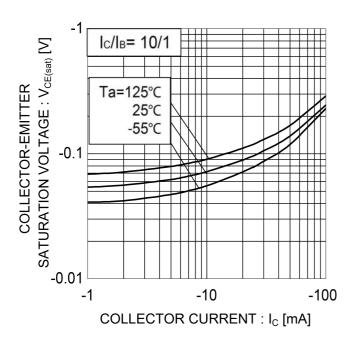


Fig.6 Collector-Emitter Saturation Voltage vs. Collector Current(II)

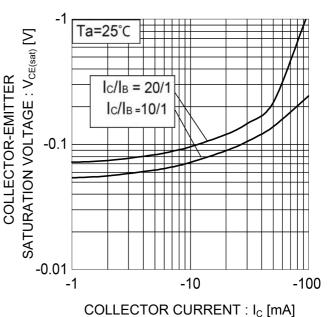


Fig.7 Base-Emitter Saturation Voltage vs.
Collector Current

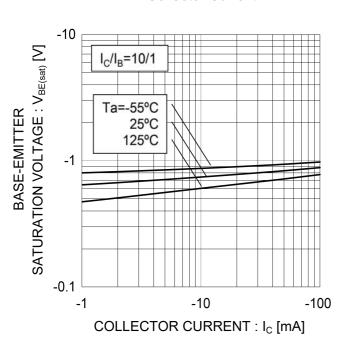
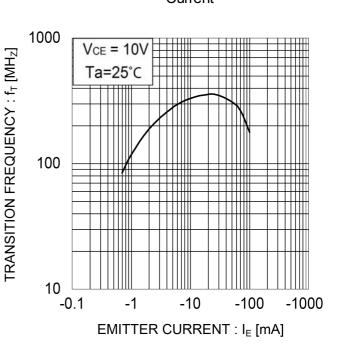


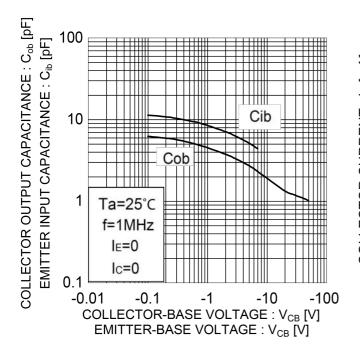
Fig.8 Gain Bandwidth Product vs. Emitter
Current

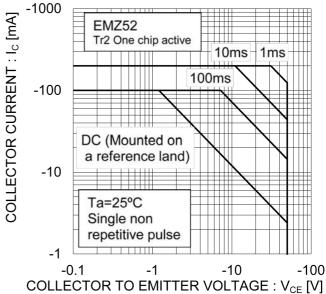


● Electrical characteristic curves (T_a = 25°C) < For Tr2(PNP)>

Fig.9 Emitter input capacitance vs. Emitter-Base Voltage Collector output capacitance vs. Collector-

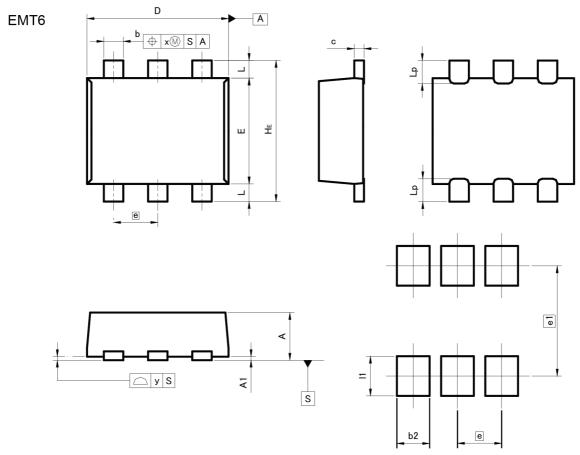
Fig.10 Safe Operating Area





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Dimensions



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM	MILIM	ETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	0.45	0.55	0.018	0.022	
A1	0.00	0.10	0.000	0.004	
b	0.17	0.27	0.007	0.011	
С	0.08	0.18	0.003	0.007	
D	1.50	1.70	0.059	0.067	
E	1.10	1.30	0.043	0.051	
е	0.	50	0.020		
HE	1.50	1.70	0.059	0.067	
L	0.10	0.30	0.004	0.012	
Lp	=	0.35		0.014	
x	-	0.10	-	0.004	
y	=	0.10	<u> </u>	0.004	

DIM	MILIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
b2	_	0.37	<u>—</u>	0.015	
e1	1.	25	0.0	049	
11	-	0.45		0.018	

Dimension in mm/inches



Notes

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